Drain Reverse Current	I_{DGO}		– 1.2		– 1.2	µA	V_{DG} = – 15V, I_S = ØA	T_A = 150°C
Drain Cutoff Current	$I_{D(OFF)}$		– 1.2		– 1.2	nA	V_{DS} = – 10V, V_{GS} = 10V	
			– 1		– 1	µA	V_{DS} = – 10V, V_{GS} = 10V	T_A = 150°C

Dynamic Electrical Characteristics

Drain Source ON Resistance	$r_{ds(on)}$		300		300	Ω	V_{GS} = ØV, I_D = ØA	f = 1 kHz
Common Source Forward Transmittance	$\lvert Y_{fs} \rvert$	4	10	5	10	mS	V_{DS} = – 10V, V_{GS} = ØV	f = 1 kHz
Common Source Input Capacitance	C_{iss}		16		12	pF	V_{DS} = – 10V, V_{GS} = ØV	f = 1 MHz
Common Source Reverse Transfer Capacitance	C_{rss}		5		3.5	pF	V_{DS} = Ø, V_{GS} = 10V	f = 1 MHz

TO-72 Package
Dimensions in Inches (mm)

Pin Configuration
1 Source, 2 Gate, 3 Drain, 4 Case

InterFET Corporation
1000 N. Shiloh Road, Garland, TX 75042
(972) 487-1287 FAX (972) 276-3375

www.interfet.co